



#### 60V NPN HIGH PERFORMANCE TRANSISTOR IN PowerDI3333-8

#### **Features**

- BV<sub>CEO</sub> > 60V
- Small Form Factor Thermally Efficient Package **Enables Higher Density End Products**
- I<sub>C</sub> = 3A High Continuous Current
- I<sub>CM</sub> = 6A Peak Pulse Current
- Low Saturation Voltage V<sub>CE(SAT)</sub> < 250mV @ 1A
- Complementary PNP Type: DXTP07060BFG
- Rated to +175°C Ideal For High Temperature Environment
- Wettable Flank For Improved Optical Inspection
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

#### **Mechanical Data**

- Case: PowerDI<sup>®</sup>3333-8
- Case Material: Molded Plastic. "Green" Molding Compound UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.03 grams (Approximate)

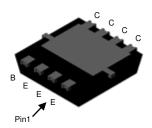
#### **Applications**

- Load Switch
- Linear Regulator

PowerDI3333-8 (SWP) (Type UX)

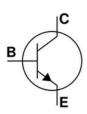


Top View



**Bottom View** 

**Equivalent Circuit** 



Device Symbol

## Ordering Information (Note 4)

Part Number	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
DXTN07060BFG-7	2H5	7	12	2,000

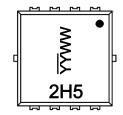
Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

  4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

### **Marking Information**

PowerDI3333-8 (SWP) (Type UX)



2H5= Product Type Marking Code YYWW = Date Code Marking YY = Last Two Digits of Year (ex: 18 = 2018) WW = Week Code (01 to 53)



### Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	80	V
Collector-Emitter Voltage	V <sub>CEO</sub>	60	V
Emitter-Base Voltage	V <sub>EBO</sub>	7	V
Continuous Collector Current	Ic	3	Α
Peak Pulse Current	I <sub>CM</sub>	6	Α

# Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
	(Note 5)		0.9	W
Power Dissipation	(Note 6)	P <sub>D</sub>	2.1	W
	(Note 7)		3.1	W
	(Note 5)		140	°C/W
Thermal Resistance, Junction to Ambient	(Note 6)	$R_{\theta JA}$	65	°C/W
	(Note 7)		44	°C/W
Thermal Resistance, Junction to Leads (No	te 8)	R <sub>0</sub> JL	8.5	°C/W
Operating and Storage Temperature Range	)	T <sub>J</sub> , T <sub>STG</sub>	-55 to +175	°C

# ESD Ratings (Note 9)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

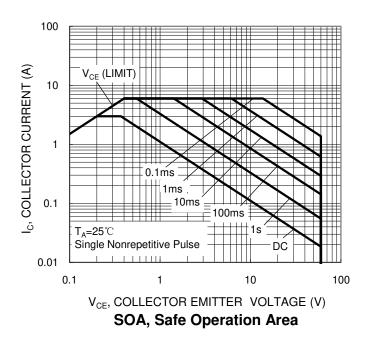
Notes: 5. For a device mounted with the collector tab on MRP FR-4 PCB; device is measured under still air conditions whilst operating in a steady-state.

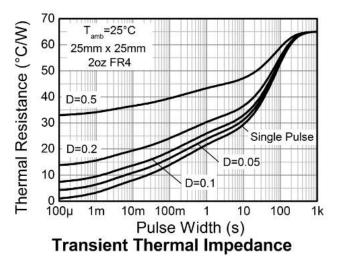
- Same as Note 5, except the device is mounted on 25mm x 25mm 2oz copper.

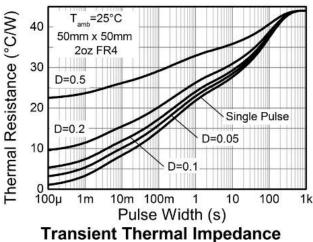
  Same as Note 5, except the device is mounted on 25mm x 50mm 2oz copper.
- Same as Note 5, except the device is mounted on somm x somm 202
   Thermal resistance from junction to solder-point (at the collector tab).
- Refer to JEDEC specification JESD22-A114 and JESD22-A115.

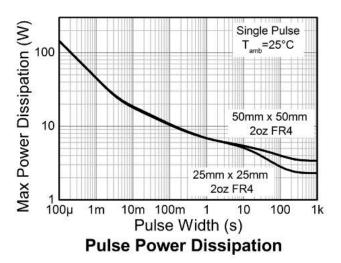


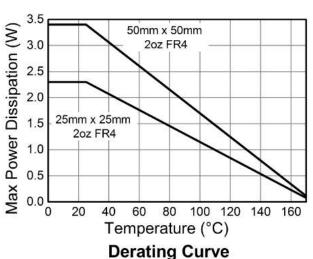
### **Thermal Characteristics and Derating Information**













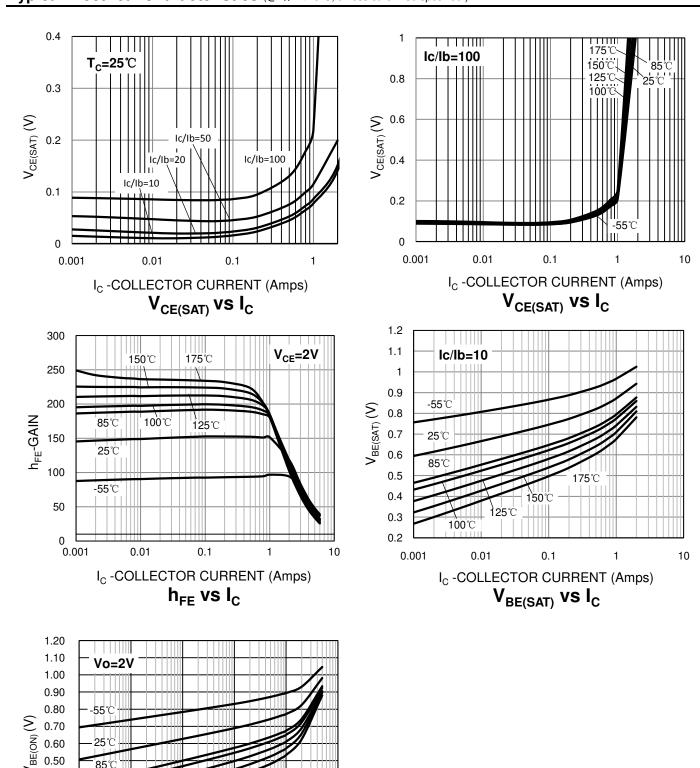
# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	80	195	_	V	$I_C = 100\mu A$
Collector-Emitter Breakdown Voltage (Note 10)	BV <sub>CEO</sub>	60	80	_	V	I <sub>C</sub> = 10mA
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	7	8.3	_	V	$I_E = 100 \mu A$
Collector Cut Off Current	I <sub>CBO</sub>	_	_	20	nA	V <sub>CB</sub> = 60V
Collector Cut-Off Current		_	_	10	μΑ	V <sub>CB</sub> = 60V, T <sub>A</sub> = +125°C
Emitter Cut-Off Current	I <sub>EBO</sub>	_	_	20	nA	V <sub>EB</sub> = 6V
Collector Emitter Seturation Voltage (Note 10)	V	_	78	250		I <sub>C</sub> = 1A, I <sub>B</sub> = 100mA
Collector-Emitter Saturation Voltage (Note 10)	V <sub>CE(SAT)</sub>	_	200	500	mV	I <sub>C</sub> = 3A, I <sub>B</sub> = 300mA
Base-Emitter Saturation Voltage (Note 10)	V <sub>BE(SAT)</sub>	_	0.86	1.1	V	I <sub>C</sub> = 1A, I <sub>B</sub> = 100mA
Base-Emitter Turn-On Voltage (Note 10)	V <sub>BE(ON)</sub>	_	0.79	0.95	V	I <sub>C</sub> = 1A, V <sub>CE</sub> = 2V
	h <sub>FE</sub>	70	152	_		I <sub>C</sub> = 50mA, V <sub>CE</sub> = 2V
DC Commant Cair (Nata 10)		100	150	300		I <sub>C</sub> = 500mA, V <sub>CE</sub> = 2V
DC Current Gain (Note 10)		80	147	_	_	I <sub>C</sub> = 1A, V <sub>CE</sub> = 2V
		40	117	_		I <sub>C</sub> = 2A, V <sub>CE</sub> = 2V
Current Gain-Bandwidth Product	f <sub>T</sub>	140	175	_	MHz	V <sub>CE</sub> = 5V, I <sub>C</sub> = 100mA, f = 100MHz
Switching Times	t <sub>ON</sub>	1	45	_	no	I <sub>C</sub> = 500mA, V <sub>CC</sub> = 10V,
Switching Times	toff		800		ns	$I_{B1} = -I_{B2} = 50 \text{mA}$
Output Capacitance	Сово	_	_	30	pF	$V_{CB} = 10V, f = 1MHz$

Note: 10. Measured under pulsed conditions. Pulse width ≤ 300µs. Duty cycle ≤ 2%.



#### Typical Electrical Characteristics (@TA = +25°C, unless otherwise specified.)



0.0001

I 0.001 0.01 0.1 1  $I_{\rm C}$  -COLLECTOR CURRENT (Amps)

 $V_{BE(ON)}$  vs  $I_C$ 

0.40 0.30 0.20 0.10 0.00

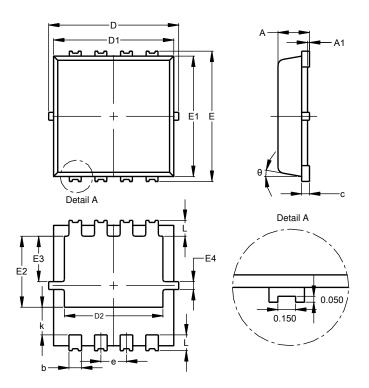
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## **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### PowerDI3333-8 (SWP) (Type UX)

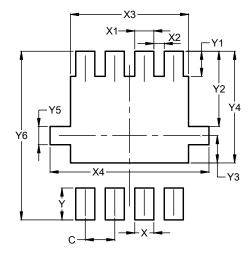


Pov	PowerDI3333-8 (SWP)						
	(Type UX)						
Dim	Min	Max	Тур				
Α	0.75	0.85	0.80				
A1	0.00	0.05					
b	0.25	0.40	0.32				
С	0.10	0.25	0.15				
D	3.20	3.40	3.30				
D1	2.95	3.15	3.05				
D2	2.30	2.70	2.50				
Е	3.20	3.40	3.30				
E1	2.95	3.15	3.05				
E2	1.60	2.00	1.80				
E3	0.95	1.35	1.15				
E4	0.10	0.30	0.20				
е	_	_	0.65				
k	0.50	0.90	0.70				
L	0.30	0.50	0.40				
θ	0°	12°	10°				
All Dimensions in mm							

### **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### PowerDI3333-8 (SWP) (Type UX)



Dimensions	Value (in mm)
С	0.650
X	0.420
X1	0.420
X2	0.230
Х3	2.600
X4	3.500
Υ	0.700
Y1	0.550
Y2	1.650
Y3	0.600
Y4	2.450
Y5	0.400
Y6	3.700

Note: For high voltage applications, the appropriate industry sector guidelines should be considered with regards to creepage and clearance distances between device terminals and PCB tracking.



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